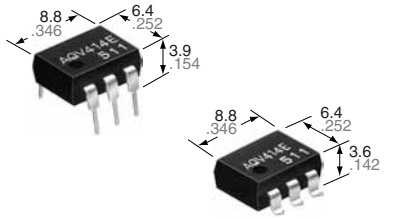
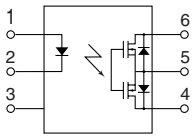
Panasonic
ideas for life

Normally closed 6-pin type of 400V load voltage

PhotoMOS®
GU 1 Form B
(AQV414)



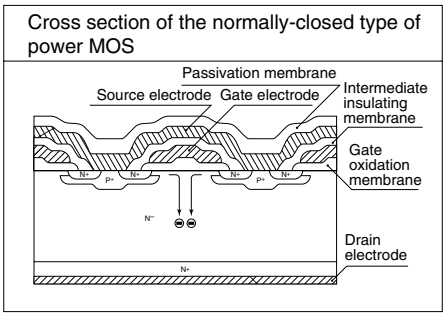
mm inch



RoHS compliant

FEATURES

1. Low on-resistance (typ. 26Ω) for normally-closed type
This has been achieved thanks to the built-in MOSFET processed by our proprietary method, DSD (Double-diffused and Selective Doping) method.



2. Controls low-level analog signals
PhotoMOS feature extremely low closed-circuit offset voltage to enable control of low-level analog signals without distortion.

3. High sensitivity and low on-resistance
Can control max. 0.15 A load current with 5 mA input current.

4. Low-level off state leakage current of max. 1 μA

TYPICAL APPLICATIONS

- Security equipment
- Telephone equipment (Dial pulse)
- Measuring instruments

TYPES

	I/O isolation voltage	Output rating*		Package	Part No.				Packing quantity	
					Through hole terminal	Surface-mount terminal				
					Tube packing style		Tape and reel packing style		Tube	Tape and reel
		Load voltage	Load current				Picked from the 1/2/3-pin side	Picked from the 4/5/6-pin side		
AC/DC dual use	1,500 V AC	400 V	120 mA	DIP6-pin	AQV414	AQV414A	AQV414AX	AQV414AZ	1 tube contains: 50 pcs. 1 batch contains: 500 pcs.	1,000 pcs.

*Indicate the peak AC and DC values.
Note: The surface mount terminal shape indicator “A” and the packing style indicator “X” or “Z” are not marked on the device.

RATING

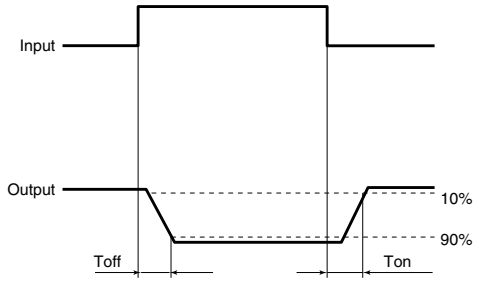
1. Absolute maximum ratings (Ambient temperature: 25°C 77°F)

Item		Symbol	Type of connection	AQV414(A)	Remarks
Input	LED forward current	I_F		50 mA	
	LED reverse voltage	V_R		5 V	
	Peak forwrd current	I_{FP}		1 A	f = 100 Hz, Duty factor = 0.1%
	Power dissipation	P_{in}		75 mW	
Output	Load voltage (peak AC)	V_L		400 V	
	Continuous load current	I_L	A	0.12 A	A connection: Peak AC, DC B, C connection: DC
			B	0.13 A	
			C	0.15 A	
	Peak load current	I_{peak}		0.3 A	A connection: 100 ms (1 shot), V_L = DC
	Power dissipation	P_{out}		500 mW	
Total power dissipation		P_T		550 mW	
I/O isolation voltage		V_{iso}		1,500 V AC	
Temperature limits	Operating	T_{opr}		–40°C to +85°C –40°F to +185°F	Non-condensing at low temperatures
	Storage	T_{stg}		–40°C to +100°C –40°F to +212°F	

2. Electrical characteristics (Ambient temperature: 25°C 77°F)

Item			Symbol	Type of connection	AQV414(A)	Condition
Input	LED operate (OFF) current	Typical	I_{Foff}	—	1.0 mA	I_L = Max.
		Maximum			3.0 mA	
	LED reverse (ON) current	Minimum	I_{Fon}	—	0.4 mA	I_L = Max.
		Typical			0.95 mA	
	LED dropout voltage	Typical	V_F	—	1.25 V (1.14 V at I_F= 5 mA)	I_F = 50 mA
		Maximum			1.5 V	
Output	On resistance	Typical	R_{on}	A	26 Ω	I_F = 0 mA I_L = Max. Within 1 s on time
		Maximum			50 Ω	
		Typical	R_{on}	B	20 Ω	I_F = 0 mA I_L = Max. Within 1 s on time
		Maximum			25 Ω	
		Typical	R_{on}	C	10 Ω	I_F = 0 mA I_L = Max. Within 1 s on time
		Maximum			12.5 Ω	
	Off state leakage current	Maximum	I_{Leak}	—	1 μA	I_F = 5 mA V_L = Max.
Transfer characteristics	Operate (OFF) time*	Typical	T_{off}	—	0.47 ms	I_F = 0 mA → 5 mA I_L = 120 mA
		Maximum			1.0 ms	
	Reverse (ON) time*	Typical	T_{on}	—	0.28 ms	I_F = 5 mA → 0 mA I_L = 120 mA
		Maximum			1.0 ms	
	I/O capacitance	Typical	C_{iso}	—	0.8 pF	f = 1 MHz V_B = 0 V
		Maximum			1.5 pF	
	Initial I/O isolation resistance	Minimum	R_{iso}	—	1,000 MΩ	500 V DC

*Operate/Reverse time



RECOMMENDED OPERATING CONDITIONS

Please obey the following conditions to ensure proper device operation and resetting.

Item	Symbol	Recommended value	Unit
Input LED current	I_F	5	mA

■ For Dimensions.
■ For Schematic and Wiring Diagrams.
■ For Cautions for Use.

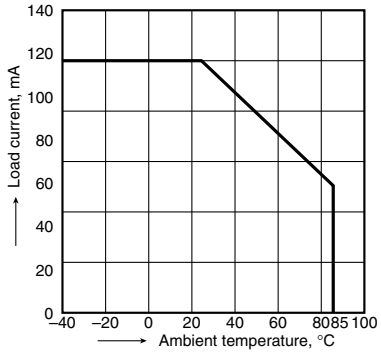
■ These products are not designed for automotive use.
If you are considering to use these products for automotive applications, please contact your local Panasonic Corporation technical representative.
For more information.

REFERENCE DATA

1. Load current vs. ambient temperature characteristics

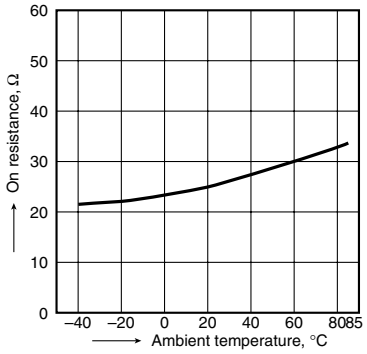
Allowable ambient temperature: –40°C to +85°C
–40°F to +185°F

Type of connection: A



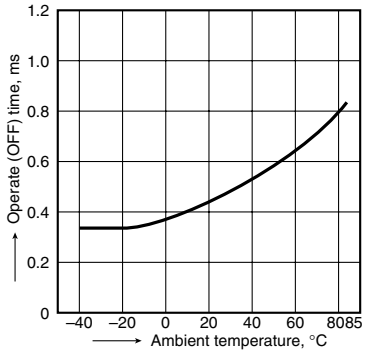
2. On resistance vs. ambient temperature characteristics

Measured portion: between terminals 4 and 6;
LED current: 0 mA;
Continuous load current: 120 mA (DC)



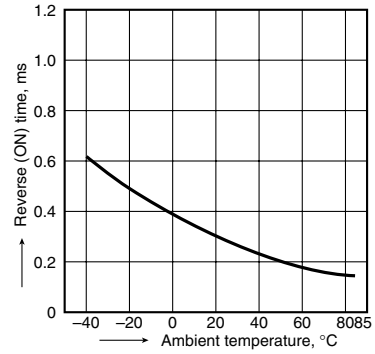
3. Operate (OFF) time vs. ambient temperature characteristics

LED current: 5mA;
Load voltage: 400 V (DC);
Continuous load current: 120 mA (DC)



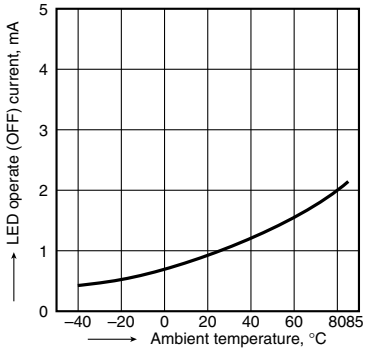
4. Reverse (ON) time vs. ambient temperature characteristics

LED current: 5 mA; Load voltage: 400 V (DC);
Continuous load current: 120 mA (DC)



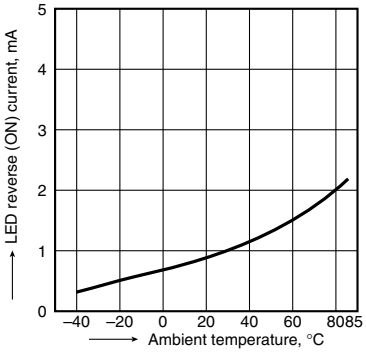
5. LED operate (OFF) current vs. ambient temperature characteristics

Load voltage: 400 V (DC);
Continuous load current: 120 mA (DC)



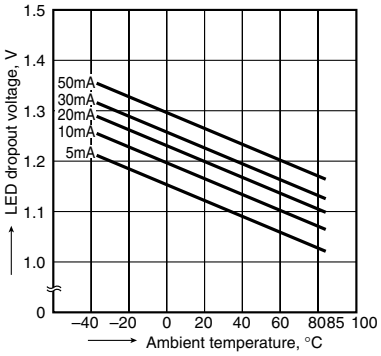
6. LED reverse (ON) current vs. ambient temperature characteristics

Load voltage: 400 V (DC);
Continuous load current: 120 mA (DC)



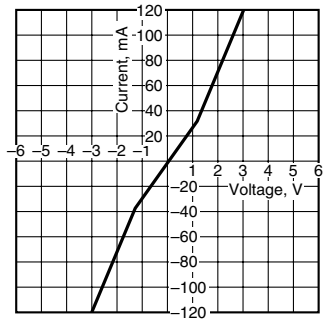
7. LED dropout voltage vs. ambient temperature characteristics

LED current: 5 to 50 mA



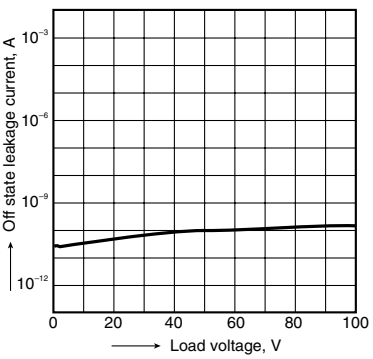
8. Current vs. voltage characteristics of output at MOS portion

Measured portion: between terminals 4 and 6;
Ambient temperature: 25°C 77°F



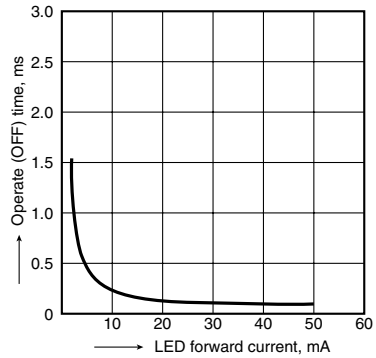
9. Off state leakage current vs. load voltage characteristics

Measured portion: between terminals 4 and 6;
LED current: 5 mA; Ambient temperature: 25°C 77°F



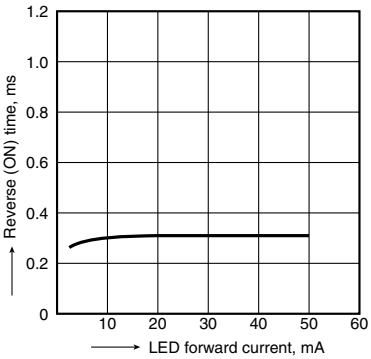
10. Operate (OFF) time vs. LED forward current characteristics

Measured portion: between terminals 4 and 6;
Load voltage: 400 V (DC); Continuous load current: 120 mA (DC); Ambient temperature: 25°C 77°F



11. Reverse (ON) time vs. LED forward current characteristics

Measured portion: between terminals 4 and 6;
Load voltage: 400 V (DC); Continuous load current: 120 mA (DC); Ambient temperature: 25°C 77°F



12. Output capacitance vs. applied voltage characteristics

Measured portion: between terminals 4 and 6;
Frequency: 1 MHz; Ambient temperature: 25°C 77°F